

THR60U06SK



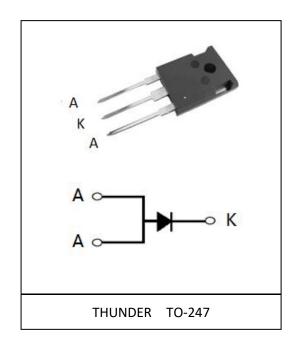
Thunder High Power Products

FRED Ultrafast Soft Recovery Diode, 60A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction

Product Summary			
VR	600 V		
lf(AV)	60A		
trr	32ns		



Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	60	
Single pulse forward current	IFSM	Tc =25°C	600	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	120	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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Electrical characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units	
Breakdown voltage	VBR,	Ir=100µA	600				
Blocking voltage	V _R	IN-130/ /\					
Forward voltage V		IF=60A		1.45	1.80	V	
	VF	IF=60A, Tj =125°C		1.30	1.70		
Reverse leakage current		VR= VRRM			50		
	lR l	Tj=150°C, V _R =600V			500	μ Α	
Reverse recovery	. trr	I _F =0.5A, I _R =1A, I _{RR} =0.25A		50	70		
time		I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		32	45	ns	
Reverse recovery	trr			55		ns	
time	•	L =604 V =200V					
Maximum Reverse	IRM	I _F =60A,V _R =300V,		5		А	
Recovery Current	IIVIVI	$d_{IF}/dt = -200A/\mu s$,T _J =25 $^{\circ}$ C					
Reverse Recovery	Orr	Qrr		346		nC	
Charge	Qii		340		IIC		
Reverse recovery	trr			132		ns	
time	C.I.				132		113
Maximum Reverse	IRM	I _F =60A,VR =300V,		12		Α	
Recovery Current	ILVIAI	$d_{IF}/dt = -200A/μs$, T_{J} =125 $^{\circ}$ C		12		A	
Reverse Recovery	Qrr			1000		6	
Charge				1960		nC	

Thermal characteristics

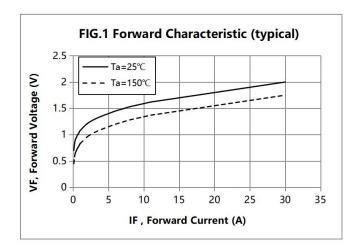
Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{ heta$ JC	0.75	°C/W

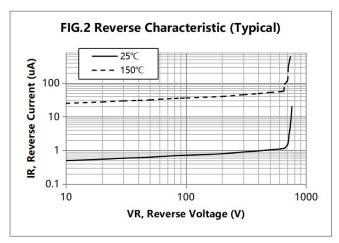
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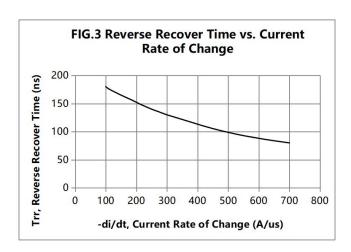


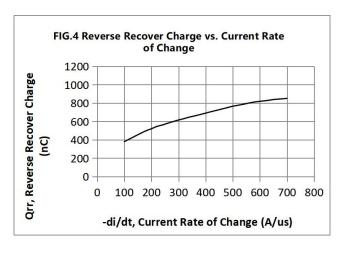


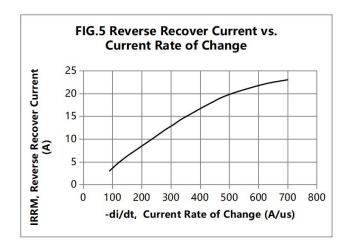
Electrical performance (typical)

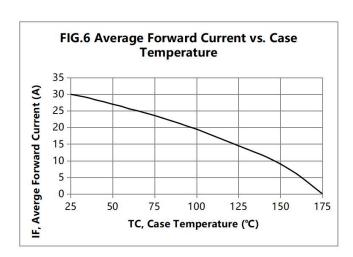












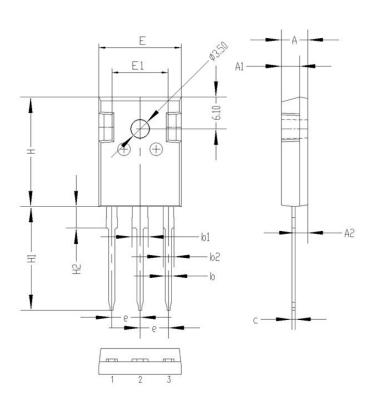
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Package Information

TO-247 PACKAGE



Symbol	Dimensions(millimeters)		
Symbol	Min.	Max.	
А	4.80	5.20	
A1	3.30	3.70	
A2	2.10	2.50	
b	1.00	1.40	
b1	2.90	3.30	
b2	1.90	2.30	
С	0.40	0.80	
е	5.25	5.65	
Е	15.6	16.0	
E1	10.6	11.00	
Н	20.8	21.2	
H1	19.4	20.4	
H2	3.90	4.30	
G	5.90	6.30	
ΦР	3.30	3.70	

Notice

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